# Thermal and Electrical Properties of  $Nb<sub>2</sub>AIC$ , (Ti,  $Nb<sub>2</sub>AIC$ and Ti<sub>2</sub>AIC

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The heat capacities, thermal-expansion coefficients, thermal and electrical conductivities of  $Nb<sub>2</sub>AIC$ (actual Nb:Al:C mole fractions:  $0.525 \pm 0.005$ ,  $0.240 \pm 0.002$ , and  $0.235 \pm 0.005$ , respectively), T<sub>12</sub>AlC and (Ti, Nb)<sub>2</sub>AlC (actual Ti:Nb:Al:C mole fractions: 0.244  $\pm$  0.005, 0.273  $\pm$  0.005, 0.240  $\pm$ 0.003, and 0.244  $\pm$  0.005, respectively) were measured as a function of temperature. These ternaries are good electrical conductors, with a resistivity that increases linearly with increasing temperatures. The resistivity of  $(T_i, Nb)_2$ AlC is higher than the other members, indicating a solid-solution scattering effect. The thermal-expansion coefficients, in the 25  $\degree$ C to 1000  $\degree$ C temperature range, are comparable and fall in the narrow range of 8.7 to 8.9  $\times$  10<sup>-6</sup> K<sup>-1</sup>, with that of the solid solution being the highest. They are all good conductors of heat, with thermal conductivities in the range between 15 to 45 W/m K at room temperature. The electronic component of the thermal conductivity is the dominant mechanism at all temperatures for  $Nb<sub>2</sub>AIC$  and (Ti, Nb)<sub>2</sub>AlC. The conductivity of Ti<sub>2</sub>AlC, on the other hand, is high because the phonon contribution to the conductivity is nonnegligible.

and thermal-expansion coefficients (TECs) were affected by <br>the formation of the solid solution, the electrical properties **II. EXPERIMENTAL PROCEDURE** were much less altered. Mixtures of graphite  $(-325 \text{ mesh}, 99 \text{ pet})$ , Al<sub>4</sub>C<sub>3</sub>  $(-325 \text{ mesh}, 99 \text{ pet})$ 

**I. INTRODUCTION** This is one reason, for example,  $Ti_4AlN_{2.9}$ , is a poorer phonon conductor than  $Ti_2AlC^{[1]}$ . The second reason is more unique THE ternary carbides Nb<sub>2</sub>AlC and T<sub>1</sub><sub>2</sub>AlC belong to a<br>larger class of solids with the general formula  $M_{N+1}AX_N$ ,<br>where  $N = 1$  to 3, M is an early transition metal, A is an<br>A-group (mostly III and IV A) element, and X

to thermal shock and damage tolerant. Some of them also<br>exhibit some very attractive high-temperature properties.<br>Nowotny and co-workers<sup>[17,18]</sup> were the first to synthesize<br>and fully characterize all the known MAX phase

In general, the MAX phases are good thermal conductors mesh, 99.0 pct+), Nb ( $1-5 \mu m$ , 99.8 pct), and Ti ( $-325 \text{ cause they are good electrical conductors}$ . The pho-<br>resh, 99.5 pct) powders were used in this work. The purities, because they are good electrical conductors.<sup>[5,10,14]</sup> The pho-<br>non contribution to the total conductivity, with a few notable based on metal basis alone, are those specified by the supplier non contribution to the total conductivity, with a few notable based on metal basis alone, are those specified by the supplier<br>exceptions. Ti-AIC being one of them is small despite the (Alpha Aesar, Ward Hill, MA). The pro exceptions, T<sub>12</sub>AlC being one of them, is small, despite the (Alpha Aesar, Ward Hill, MA). The processing details for fact that these solids are elastically stiff and have high Debye the T<sub>12</sub>AlC and the Nb-containing sa temperatures.<sup>[6,16]</sup> The phonon contribution is suppressed<br>because of two factors. First, the presence of small concentra-<br>were mixed in the proper stoichiometry, cold isostatically because of two factors. First, the presence of small concentra-<br>tions of point defects which, not unlike the binary near-<br>pressed, sealed in glass under vacuum, and placed in a hot tions of point defects which, not unlike the binary near-<br>stochastic pressed, sealed in glass under vacuum, and placed in a hot<br>stoichiometric MX phases, are potent phonon scatterers.<sup>[20,21]</sup> isostatic press (HIP). The T  $\approx$  40 MPa for 16 hours at 1300 °C and the Nb<sub>2</sub>AlC and (Ti, Nb)<sub>2</sub>AlC samples at  $\approx$  100 MPa for 8 hours at 1600 °C. M.W. BARSOUM, Professor, I. SALAMA, and T. EL-RAGHY are with The samples were sliced, mounted, and polished down to a the Department of Materials Engineering, Drexel University, Philadelphia, 1-*um* diamond suspension for with the Oak Ridge National Laboratory, Oak Ridge, TN 37831. was performed on a Cameca SX100 (Paris). Measurements<br>Manuscript submitted November 9, 2001. were carried out using an accelerating voltage of 20 kV, and were carried out using an accelerating voltage of 20 kV, and

the Department of Materials Engineering, Drexel University, Philadelphia,  $1-\mu m$  diamond suspension for optical and scanning electron<br>PA 19104. Contact e-mail: barsoumw@drexel.edu J. GOLCZEWSKI, microscopy (SEM). The chemi PA 19104. Contact e-mail: barsoumw@drexel.edu J. GOLCZEWSKI, microscopy (SEM). The chemical composition was meas-<br>H.J. SEIFERT, and F. ALDINGER are with the Max Planck Institut fur metal wed by electron probe X-ray microan

a probe current of 10 nA. The  $K_{\alpha}$  lines from the following standards were used for the quantitative analysis: pure Ti for Ti metal and Fe<sub>3</sub>C for C. The standard for Nb was Nb metal, where the  $L_{\alpha}$  line was used instead.

The densities,  $\delta$ , of the hipped samples were measured using Archimedes' method in water at ambient temperatures. The resistances were measured using a four-probe technique at 290, 273.15, 77, and 4.2 K. The coefficients of thermal expansions of bulk samples  $(4 \times 4 \times 25 \text{ mm}^3)$  were measured under flowing Ar (25 mL/min) in the 25  $\degree$ C to 1200 8C temperature range using a dilatometer (Unitherm, Anter Corp., Pittsburgh, PA). The thermal strains were measured, both on heating and cooling, at a rate of  $2 °C/min$ . The dilatometer was precalibrated, and the error in the measurements is estimated to be  $\approx$  2 pct.

The heat capacities and thermal diffusivities,  $D$ , of  $Ti<sub>2</sub>AIC$ were measured using the equipment and procedures described in Reference 5; the corresponding values for the other two samples were measured using a different calorimeter and a different laser-flash system. The former was meas-<br>ured using a differential scanning calirometer (DSC) Fig. 1—Temperature dependence of resistivity in the 4.2 to 300 K range. (Netzsch, 404C, Selb, Germany). The DSC was calibrated using a sapphire crystal; the calibration and all measurements grain size of  $\approx$  14  $\mu$ m. The samples were fully dense, with a measured density ( $\delta$  = 6.37  $\pm$  0.02 Mg/m<sup>3</sup>) that is 98% The samples were cylindrical (5 The samples were cylindrical (5-mm diameter,  $\approx$  1-mm of value calculated from the lattice parameters.<br>thick). For the laser-flash technique, a flat cylindrical sample The starting composition for the solid solution was ture; at which time, the front surface was pulsed, for  $1 \approx 1$  vol pct of Nb-Ti carbides and aluminides. According to ms, with a 40 J pulse of a Nd:YAG laser. The increase EPMA results, the actual Ti, Nb, Al, and C mole f in temperature on the rear surface was monitored with a were  $0.244 \pm 0.005$ ,  $0.273 \pm 0.005$ ,  $0.240 \pm 0.003$ , and pyrometer, and the temperature vs time curve was digitized  $0.244 + 0.005$ , respectively. Once again, assu pyrometer, and the temperature vs time curve was digitized<br>and analyzed to estimate the half-time lag,  $t_{1/2}$ , between the<br>initial and the stable final temperatures. The D values are<br>initial and the stable final tempera calculated assuming,  $D = 0.134 d^2/t_{1/2}$ . The *Ds* are then calculated assuming,  $D = 0.134 d^2/t_{1/2}$ . The *Ds* are then<br>converted to thermal conductivities,  $k_{\text{tot}}$ , using the relation-<br>ship:  $k_{\text{tot}} = c_p D\delta$ .<br>converted to thermal conductivities,  $k_{\text{tot}}$ , using the relation-<br>de

## A. *Microstructural Characterization*

The Ti<sub>2</sub>AlC samples were fully dense, measured density, B. Electrical Properties  $\delta$  = 4.1 Mg/m<sup>3</sup>, with an average grain size of  $\approx$  25  $\mu$ m.  $\delta = 4.1$  Mg/m<sup>3</sup>, with an average grain size of  $\approx 25$   $\mu$ m. The temperature dependencies of the resistivities,  $\rho$ , are Optical and SEM micrographs of the resulting microstruc-<br>Diotted in Fig. 1. Like all MAX phases graphs revealed that in addition to the  $Ti<sub>2</sub>AIC$  matrix, two sented by: minority phases, most likely  $Al_2O_3$  and  $Ti_3P<sub>i</sub><sup>[9]</sup>$  with a total volume fraction of  $\approx$ 4 vol. pct exist. The EPMA indicated that the final composition was close to the stoichiometric where  $\rho_0$ ,  $\alpha$ , and *T* are, respectively, the resistivity at the

mole fractions, as determined by EPMA were  $0.525 \pm 0.005$ , only valid for temperatures  $>70$  K. 0.240  $\pm$  0.002, and 0.235  $\pm$  0.005, respectively. If one The resistivity of the solid solution is significantly higher



a measured density ( $\delta = 6.37 \pm 0.02$  Mg/m<sup>3</sup>) that is 98%

dense; the measured density  $(5.3 \pm 0.05 \text{ Mg/m}^3)$  is in excellent agreement with theoretical value calculated from **III.** RESULTS AND DISCUSSION the lattice parameters, *viz.* 5.28 Mg/m<sup>3</sup>.<sup>[19]</sup> The grains are platelike, with an average size of 50 to 60  $\mu$ m.

plotted in Fig. 1. Like all MAX phases [1],  $\rho$  increases ture can be found elsewhere.<sup>[9]</sup> Backscattered SEM micro-<br>linearly with increasing temperatures and can be repre-

$$
\rho = \rho_0 [1 + \alpha (T - T_{\text{ref}})]
$$

composition, T<sub>12</sub>AlC.<br>To obtain phase-pure samples of Nb<sub>2</sub>AlC, over a dozen resistivity, and the temperature in degrees Kelvin. Least To obtain phase-pure samples of  $Nb<sub>2</sub>AlC$ , over a dozen resistivity, and the temperature in degrees Kelvin. Least different compositions were explored.<sup>[15]</sup> The nominal com-<br>squares fits of the results, shown in Figur squares fits of the results, shown in Figure 1, yield the values position that resulted in predominantly single-phase samples listed in Table I. In all cases, the reference temperature is was  $Nb_{1.95}Al_{1.05}Co_{0.95}$ . However, the actual Nb, Al, and C 2300 K and  $R^2 > 0.999$ . Note that these relationships are

assumes the Nb sites to be fully occupied, the resulting than its end members, which implies that solid-solution scatcompound is best represented as  $Nb_{2.00}Al_{0.91}C_{0.89}$ . In other tering is occurring in this system. In contrast, when the words, it is postulated that vacancies exist on the Al and resistivities of T<sub>12</sub>AlN, T<sub>12</sub>AlN<sub>0.</sub> words, it is postulated that vacancies exist on the Al and resistivities of Ti<sub>2</sub>AlN, Ti<sub>2</sub>AlN<sub>0.5</sub>C<sub>0.5</sub>, and Ti<sub>2</sub>AlC are com-<br>C sites. The resulting predominantly single-phase samples pared, the solid solution appears pared, the solid solution appears to fall on the line joining contained  $\approx$  2 vol pct Al<sub>2</sub>O<sub>3</sub> and  $\approx$  1 vol pct Nb-carbides the end members.<sup>[9]</sup> It, thus, appears that the effect of substi-<br>and aluminides. The grains were equiaxed with an average tutions on the M sites on the e tutions on the M sites on the electrical conductivity is greater

**Table I.** Values of  $\rho_0$  ( $\mu\Omega$ m) and  $\alpha$  (K)<sup>-1</sup> and the Coefficients of a Second-Order Polynomial Assuming  $\Delta L/L_0 = A + B$ **T(K)** 1 **CT2 . The Conductivity Results are Only Valid for Temperatures** .**70 K and the Thermal Expansion in the 400–1500 K Temperature Range.**

Compound	$\mu_0$ $(\mu\Omega m)$	$\alpha$ $(K)^{-1}$	Ref. Temp.				$\mathbf{D}^2$
Nb <sub>2</sub> AIC	0.29	0.0024	300 K	$-1.6 \times 10^{-3}$	$-4.0 \times 10^{-6}$	$2.4 \times 10^{-9}$	> 0.99
$(Ti, Nb)$ , AlC	0.78	0.001	300 K	$-1.8 \times 10^{-3}$	$-4.5 \times 10^{-6}$	$2.34 \times 10^{-9}$	> 0.99
Ti <sub>2</sub> AIC	0.36	0.0035	300 K	$-1.4 \times 10^{-3}$	$-3.3 \times 10^{-6}$	$2.7 \times 10^{-9}$	> 0.99



two solid solutions, and consequently, its general validity 2(b)).

MAX phases measured to date,<sup>[1]</sup> the values reported here  $\qquad$  3. The solid and dotted lines in Figure 3 represent the best



Fig. 3—Temperature dependence of heat capacities. The data were fit to the Debye model, which results in the various lines superimposed on the data. For Ti<sub>2</sub>AlC, the data points above  $\approx$ 900 K were not used in the fit (text). To obtain the results listed in Table III, the lines were fit to a thirdorder polynomial.

for  $Nb<sub>2</sub>AIC$  are relatively high. Such high values are consistent with a structure in which the concentration of defects, in general, and point defects, in particular, are large, *i.e.*, consistent with the proposed structure,  $Nb_{2.00}Al_{0.91}C_{0.89}$ .

## C. *Thermal Properties*

The thermal expansions (on heating and cooling) of the two end members are almost indistinguishable, and both are slightly lower than the solid solution (Figure 2). Least squares fitting of all points (heating and cooling) yields the following TECs:  $8.7 \times 10^{-6}$ K<sup>-1</sup> for Nb<sub>2</sub>AlC,  $8.7 \times 10^{-6}$ K<sup>-1</sup> for T<sub>12</sub>AlC, and  $8.9 \times 10^{-6}$ K<sup>-1</sup> for the (Ti, Nb)<sub>2</sub>AlC. The (*b*)  $R^2$  values in all cases was  $> 0.98$ . Given the curvature, a Fig. 2—(*a*) Temperature dependence of thermal expansions upon heating better fit can be obtained by a second order polynomial; the and cooling. The data for the solid solution are shifted upward by a strain coefficients o and cooling. The data for the solid solution are shifted upward by a strain coefficients of which are also listed in Table I. Here, the of 0.002 and those for Ti<sub>2</sub>AIC by 0.004. Least-squares fits of the results  $R^2$  val of 0.002 and those for T<sub>2</sub>AIC by 0.004. Least-squares fits of the results<br>are shown by lines superimposed on the data. The inset superimposes the<br>results of the polynomial fits (text and Table I). (b) Comparison of TCEs<br> binary carbides, MX. much more subtle, however (inset in Figure 2(a)). In contrast to the Sn and Pb-containing  $(211)$  phases,<sup>[11]</sup> there is little correlation between the TECs of the MAX phases and their than those on the X sites. This conclusion is based on only respective binary near-stoichiometric MX phases (Figure

The temperature dependence of the heat capacities,  $c_p$ , of<br>When compared to the residual resistivities of the other the end members and the solid solution are shown in Figure the end members and the solid solution are shown in Figure

Table II. Coefficients of Third-Order Polynomial Used to Fit the  $c_p$  Results after They Were Fit to the Debye Model. The **Relevant Equation is:**  $c_p = A + \overrightarrow{B} T(K) + CT^2 + DT^3$ .

Compound					Temp. Range (K)
Ti <sub>2</sub> AIC	58.1	0.10	$-7.0 \times 10^{-5}$	$1.8 \times 10^{-8}$	$300 - 1600$
$(T_i, Nb)$ , AlC	74.8	0.06	$-4.3 \times 10^{-5}$	$1.2 \times 10^{-8}$	$300 - 1600$
Nb <sub>2</sub> AIC	59.2	0.09	$-7.3 \times 10^{-5}$	$2.0 \times 10^{-8}$	$300 - 1600$



diamonds in Figure 5) were, therefore, not used for the fitting<br>of the results (solid line). Based on the  $c_p$  results, it is unlikely<br>that the other two compositions lost Al; why that is the case<br>is not clear at this tim <sup>\*If *k<sub>ph</sub>* is not a function of temperature, then *dk*<sub>tot</sub>/dT has the same<br>in the Ar gas.<br><sup>sign</sup> as the intercept of the electrical resistivity vs T curves at 0 K.</sup>

*k*<sub>tot</sub>, is shown in Figure 4. The thermal conductivities of<br>the Nb-containing ternaries increase slightly with increasing<br>temperatures; conversely, *k*<sub>tot</sub> of T<sub>12</sub>AIC decreases. Least-<br>squares fits of the data, shown

$$
k_{\text{tot}} \text{ (Nb}_2 \text{AIC)} = 21.8 + 0.0037 \, T \quad R^2 = 0.61
$$
\n
$$
k_{\text{tot}} \text{ (Ti, Nb)}_2 \text{AIC} = 14.4 + 0.0074 \, T \quad R^2 = 0.94
$$
\n
$$
k_{\text{tot}} \text{ (Ti}_2 \text{AIC)} = 49 - 0.01 \, T \quad R^2 = 0.90
$$

Because both  $k_{\text{tot}}$  and  $\rho$  are known, the Wiedmann– Franz law:

$$
k_e = L_o T/\rho
$$

where  $L_0 = 2.45 \times 10^{-8}$  W $\Omega/K^2$ , can be used to decouple the electronic,  $k_e$ , and phonon,  $k_{ph}$ , contributions to  $k_{tot}$ . This expression has been shown to be valid for many of the MAX phases explored to date.<sup>[1]</sup> The results are summarized in Table III for two temperatures. Based on these results the following points are salient.

- (1) The Ti<sub>2</sub>AlC has the highest  $k_{\text{tot}}$  because of its high  $k_{ph}$ . Increasing the temperature reduces  $k_{ph}$  by about 60 pct.
- (2) At all temperatures, (Ti, Nb)<sub>2</sub>AlC has the lowest  $k_{\text{tot}}$ because both  $k_{ph}$  and  $k_{tot}$  are lower than the end members presumably because of solid-solution scattering. Increasing the temperature to 1300 K decreases  $k_{ph}$  by  $\approx$  50 pct.
- (3) Because for Nb<sub>2</sub>AlC, the impossible result that  $k_e$  >  $k_{\text{tot}}$ , is obtained, one must conclude that  $L_0$  < 2.45  $\times$  $10^{-8}$  W $\Omega/K^2$ . This is not unique to Nb<sub>2</sub>AlC but is true Fig. 4—Temperature dependence of thermal conductivity. The results for for other Nb-containing MAX and MX phases, such as  $\frac{\text{Ti}_3\text{SiC}_2^{[5]}}{\text{Ni}_3\text{SiC}_2^{[3]}}$  are also included for comparison.  $NbC^{[25]}$  and  $Nb<sub>2</sub>SnC^{[1,14]}$  (last two rows in Table III). Furthermore, given that it is unlikely that  $k_{ph}$  of the solid solution is greater than that of Nb<sub>2</sub>AlC, the value for the Fits of the data to the Debye model. Once generated, the<br>Debye curve was, in turn, fitted to a third-order polynomial,<br>the coefficients of which are listed in Table II.<br>The reason for the decrease in  $c_p$  at temperatures The reason for the decrease in  $c_p$  at temperatures higher<br>
The reason for the decrease in  $c_p$  at temperatures higher<br>
probably related to the loss of Al from the sample. Recent<br>
work on T<sub>12</sub>AIC is not clear at this tim
	-

in the Ar gas.<br>The effect of temperature on the thermal conductivities,<br>Thus, if the intercept is high, the slope is positive.

the Nb-containing phases,  $k_{ph}$ , is quite small, both in relation to *ke* and in absolute terms. Given the low thermal expansions, relatively high Debye temperatures and presumably

**Table III. Summary of Thermal Conductivity Results Obtained in This Work; Also Included are Literature Results for** TiC, Nb<sub>2</sub>SnC, and NbC

Compound	$k_{\text{total}}$ at		300 K		1300 K	
	300 K	1300 K	$k_e$	$k_{ph}$	$k_e$	$k_{ph}$
$TiC_{0.96}$	$14.4^{27}$	$33.4^{27}$	$7.35(50)$ pct)	$7(50 \text{ pct})$		
$TiC_{r}$	3326	3926	$12^{26}$ (36 pct)	21 (62 pct)	24 (66 pct)	$(38 \text{ pct})$ 15
Ti <sub>2</sub> AIC	46	36	20 (43 pct)	26 (57 pct)	$19.7(55 \text{ pct})$	16.3 (45 pct)
$(T_i, Nb)$ , AlC	16.6	24	9.4 $(56 \text{ pct})$	7.2 $(43 \text{ pct})$	20.3 (85 pct)	$3.7(16 \text{ pct})$
Nb <sub>2</sub> AIC	23	27	$26*(>100$ pct)		$32^*$ ( >100 pct)	
			$15.6**$ (77 pct)	$>7.4$ (32 pct)	$20**$ (73 pct)	$>4$ (26 pct)
$NbC_r$	$14^{25}$		$21^{25*}$ (>100 pct)			
Nb <sub>2</sub> SnC	$17.5^{14}$	30.5	$18**$ (>100 pct)		25 (82 pct)	$5(18 \text{ pc})$
	**Assuming Lorenz number = $1.5 \times 10^{-8}$ W $\Omega/K$ (text).		*Since $k_e > k_{\text{tots}}$ , the Lorenz number must be <2.45 × 10 <sup>-8</sup> W $\Omega/K$ (text).			

high stiffnesses, this is a somewhat surprising result. It is, **REFERENCES** however, in agreement with notion that the A atoms act as<br>
rattlers in these structures.<sup>[1]</sup> Clearly, Ti<sub>2</sub>AlC is an exception<br>
presumably because the Al atoms are strongly bound in that<br>
structure, at least at lower temp structure, at least at lower temperatures. However, based on 3. M.W. Barsoum, D. Brodkin, the TEC data, it can be argued that the Al atoms are as well and  $1997$ , vol. 36, pp. 535-41. the TEC data, it can be argued that the Al atoms are as well<br>bound in Nb<sub>2</sub>AlC as they are in Ti<sub>2</sub>AlC. Rietveld analysis<br>of high-temperature neutron or X-ray diffraction would be<br>invaluable in answering this question and

A second source of phonon scattering is point defects. It<br>well established that such defects are potent scattering of the M.C. Ho, H.H. Hamdeh, M.W. Barsoum, and T. El-Raghy: J. Appl. is well established that such defects are potent scatterers of<br>
phonons in near-stoichiometric MX phases, such as  $T_{\text{avg}}$  and  $T_{\text{avg}}$  and  $T_{\text{avg}}$  and  $T_{\text{avg}}$  and  $T_{\text{avg}}$ <br>
phonons in near-stoichiometric MX phases and  $NbC_x$ .<sup>[20,21]</sup> This is especially true here, when it is *A*, 2000, vol. 31A, p. 333. recalled that, if one assumes vacancies on the A and X 8. N. Tzenov and M.W. Barsoum: *J. Am. Cer. Soc.*, 2000, vol. 83, pp. subletting stocharaction attachment of  $\frac{\text{Al}}{\text{Al}}$   $\frac{\text{Al}}{\text{Al}}$  825-32. sublattices, the resulting stoichiometries are  $Nb_{2.00}Al_{0.91}C_{0.89}$ <br>and  $Ti_{0.94}Nb_{1.06}Al_{0.93}C_{0.94}$ . These comments notwithstanding,<br>it is hereby acknowledged that more work is needed to sort<br>in M.W. Barsoum, C.J. R out some of these issues. Most indicated at this time would<br>be low-temperature thermal-conductivity measurements and <br> $11.$  T. El-Raghy, S. Chakraborty, and M.W. Barsoum: *J. Eur. Cer. Soc.*, be low-temperature thermal-conductivity measurements and 11. T. El-Raghy, S. Chakrabort<br>neutron diffraction studies at elevated temperatures as well 2000, vol. 20, pp. 2619-25. neutron diffraction studies at elevated temperatures, as well<br>as a systematic characterization of the thermal and electrical<br>properties as a function of stoichiometry.<br> $\frac{2000, \text{ Vol. } 20, \text{ pp. } 261-82.}{12. H-I. Yoo, M.W. Barsoum, and T.$ 

To date, over a dozen MAX phases have been synthesized and T. El-Raghy: *Phys. Rev. B*, 2000, vol. 52, pp. 10194-99.<br>d characterized <sup>[1]</sup> The highest  $k_{tot}$  in the 300 to 1400 K <sup>14</sup>. M.W. Barsoum, T. El-Raghy, W.D. Porte 14. M.W. Barsoum, T. El-Raghy, W.D. Porter, H. Wang,  $\frac{1}{10}$  The highest *k*<sub>tot</sub> in the 300 to 1400 K and M.W. Barsoum, T. El-Raghy, W.D. Porter, H. Wang,  $\frac{1}{10}$  Elinelly, it is worth s. Chakraborty: *J. Appl. Phy* temperature range belongs to Ti<sub>2</sub>AlC. Finally, it is worth<br>noting that the microstructural stability of Nb<sub>2</sub>AlC is excel-<br>noting that the microstructural stability of Nb<sub>2</sub>AlC is excel-<br>2002, in press. lent; the grain size of HIP samples at  $1600 \degree$ C for 8 hours 16. P. Finkel, M.W. Barsoum, and T. El-Raghy: *J. Appl. Phys.*, 2000, vol. is  $\leq \approx 15 \mu m$ .<sup>[15]</sup> These characteristics indicate that this com-<br>87, pp. 1701-03  $\frac{87}{17}$ , pp. 1701-03.<br> **Solution**  $\frac{87}{101}$ , pp. 1701-03.<br> **IT.** H. Nowotny: *Progr. Solid State Chem.*, H. Reiss, ed., 1970, p. 27. pound is potentially an excellent candidate for high-tempera<br>ture applications. However, unless its oxidation resistance<br>ture applications. However, unless its oxidation resistance<br>vol. 94, p. 672. in air, which is poor,<sup>[28]</sup> can be enhanced, its use will have  $\frac{19.5 \times 10^{13} \text{ m}}{20.0 \text{ W.S.}}$  Movember and H. Nowotny: *Z. Metallkd.*, 1980, vol. 71, p. 341. to be confined to nonoxidizing atmospheres.

*State Chem.*, 1999, vol. 146, p. 528. We thank Professor Sommer, for carrying out the heat 24. M.W. Barsoum, J. Golczewski, H. Seifert, and F. Aldinger: *J. Alloys* capacity measurements. This work was partially funded by *Compounds*, 2002, in press.<br>
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